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METHOD THEREOF**(71) Applicant: **BOE TECHNOLOGY GROUP CO.,
LTD.**, Beijing (CN)(72) Inventor: **Liang SUN**, Beijing (CN)(21) Appl. No.: **14/436,014**(22) PCT Filed: **Aug. 7, 2014**(86) PCT No.: **PCT/CN2014/083914**

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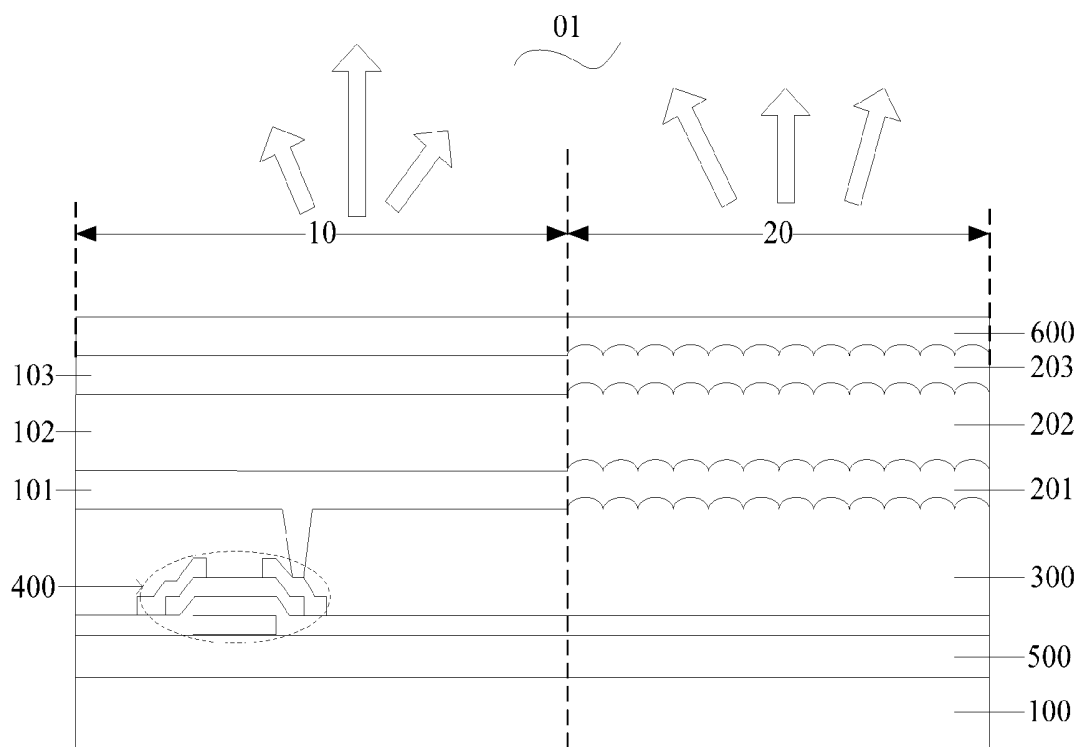
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ABSTRACT

An organic light-emitting diode (OLED) display and a manufacturing method thereof are provided. The OLED display includes a plurality of sub-pixel units each including a first region and a second region. The first region includes a first electrode, a first organic material functional layer and a second electrode disposed in order on a base substrate. The second region includes a third electrode, a second organic material functional layer and a fourth electrode disposed in order on the base substrate. The first electrode and the third electrode each include an opaque metal layer, and the second electrode and the fourth electrode are translucent metal electrodes. The first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.



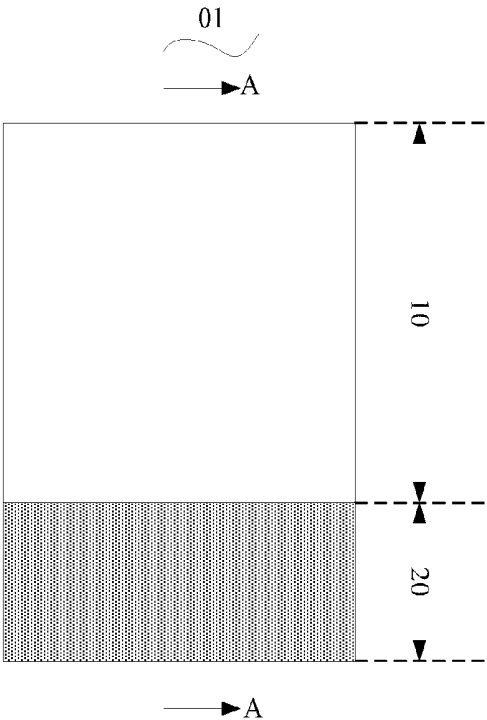


FIG.1

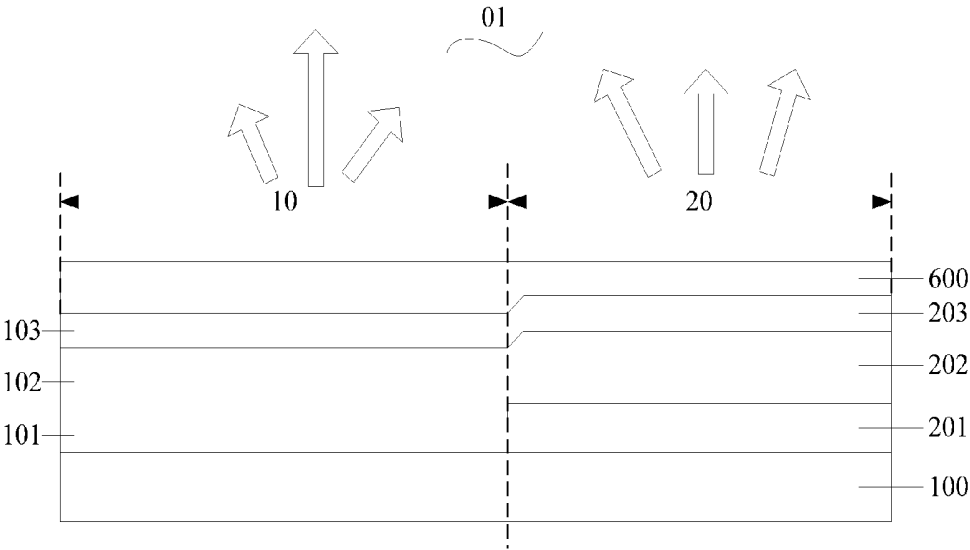


FIG.2

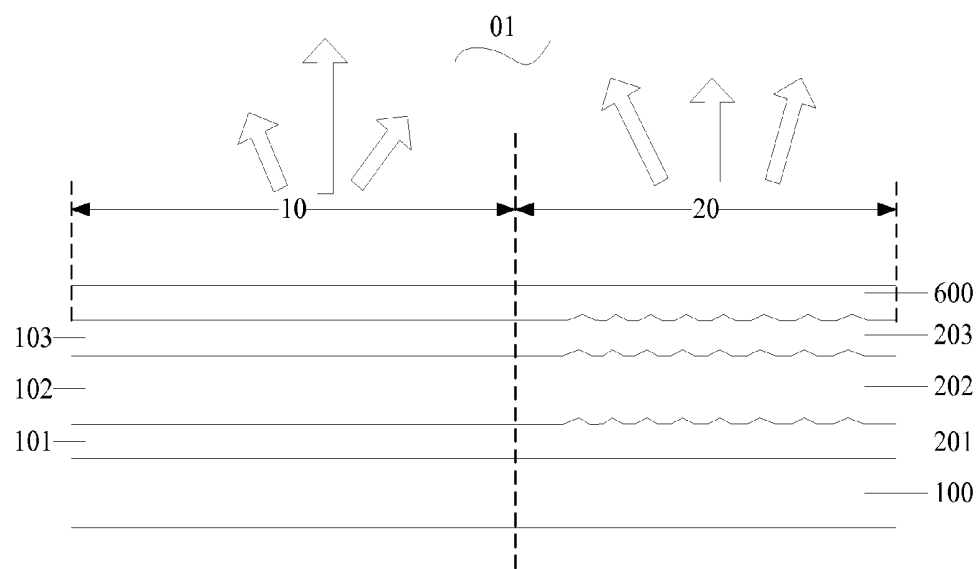


FIG.3

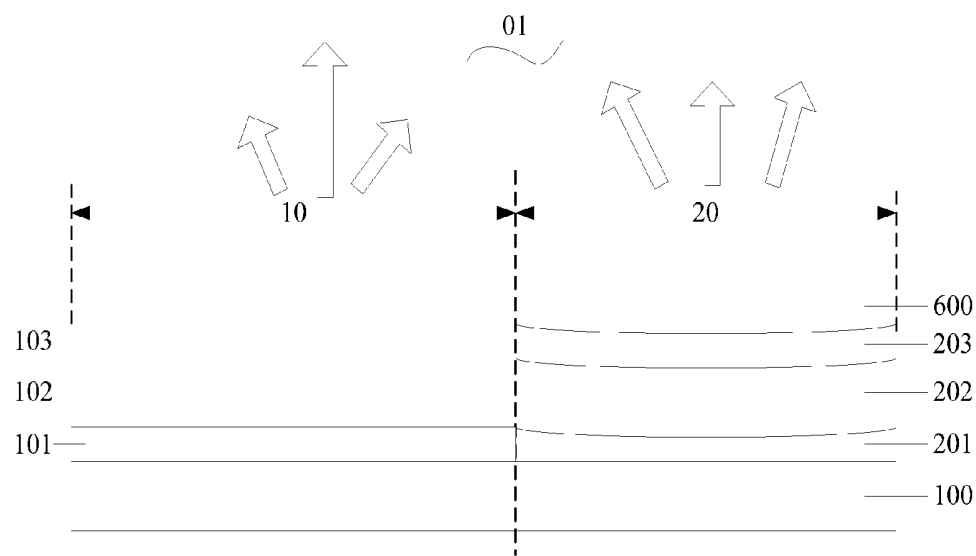


FIG.4

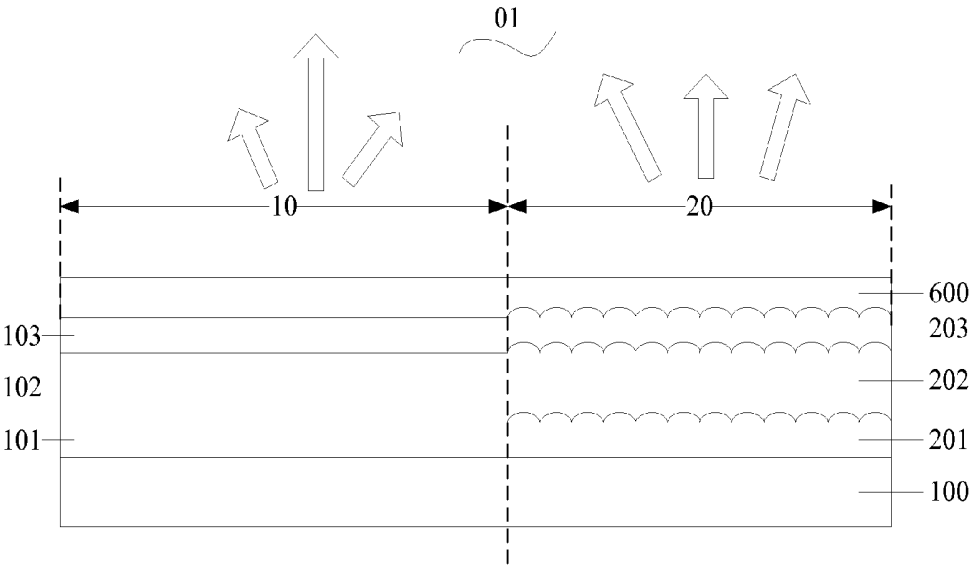


FIG.5

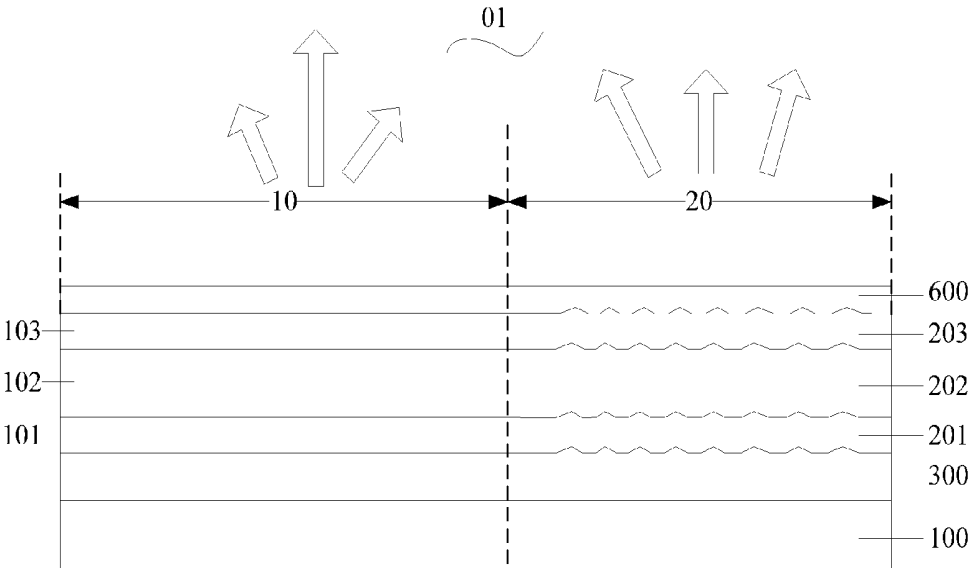


FIG.6

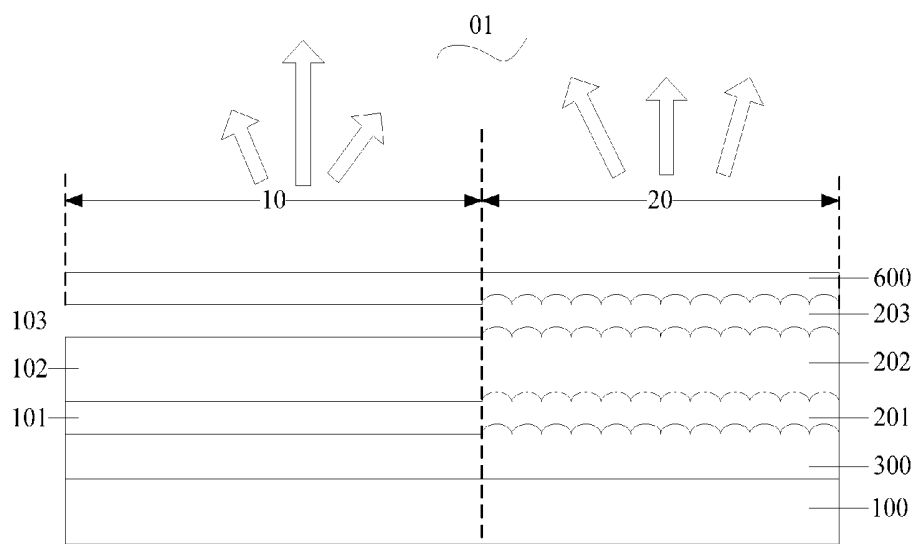


FIG.7

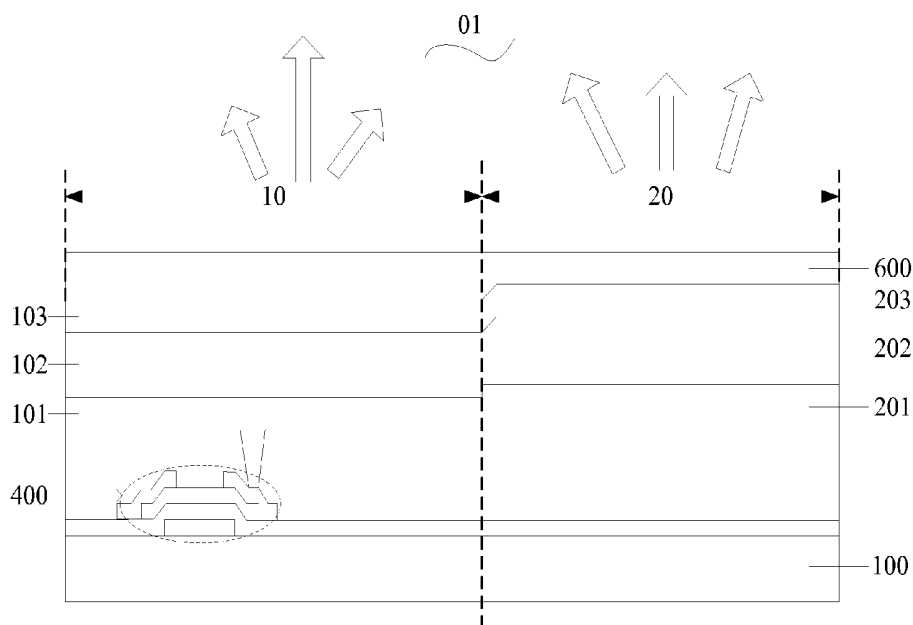


FIG.8

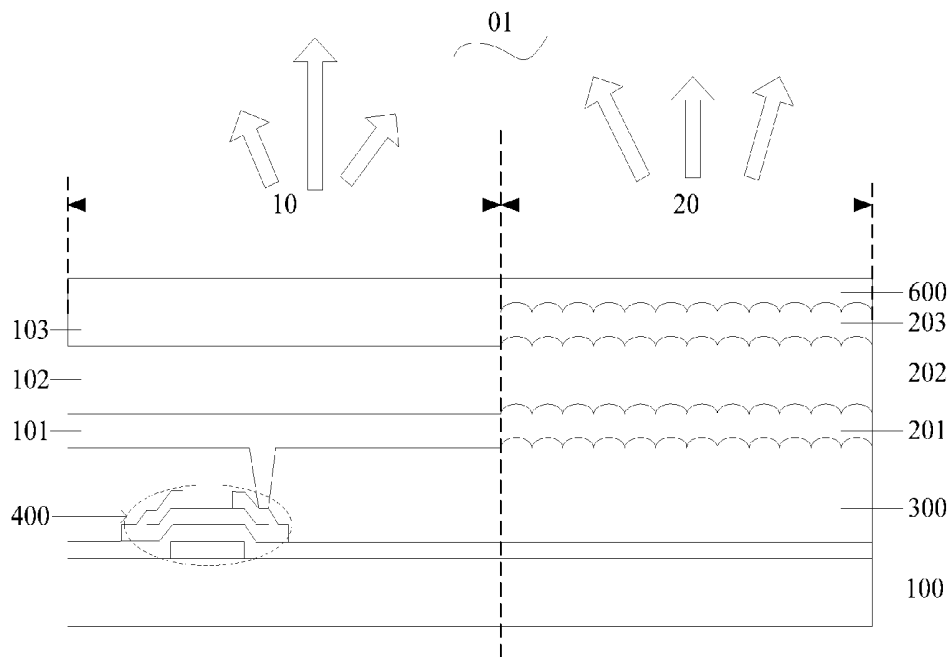


FIG.9

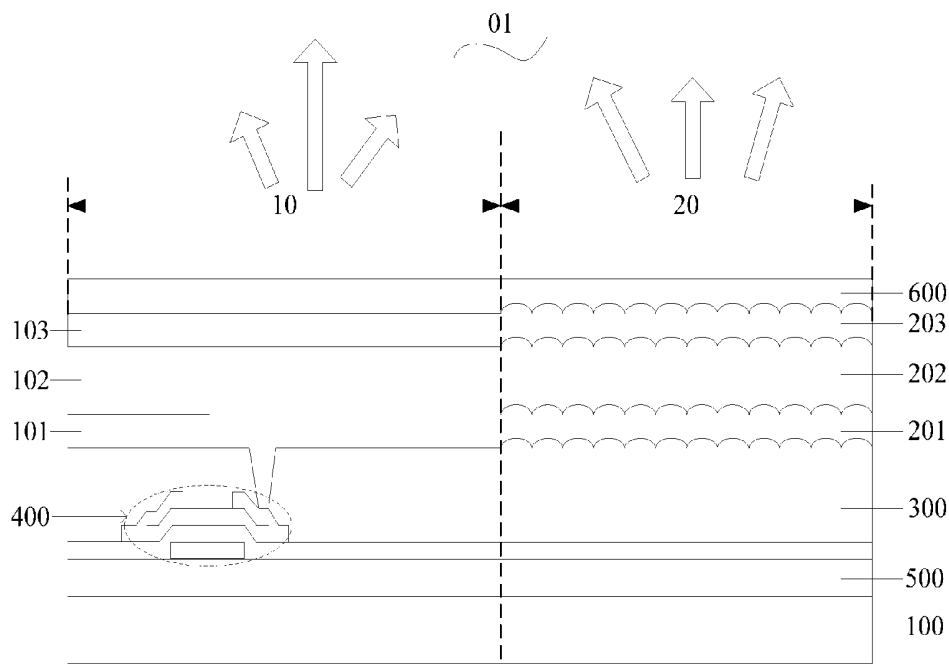


FIG.10

OLED DISPLAY AND MANUFACTURING METHOD THEREOF

TECHNICAL FIELD

[0001] Embodiments of the present invention relate to an organic light emitting diode (OLED) display and a manufacturing method thereof.

BACKGROUND

[0002] Organic light emitting diode (OLED) is an organic film electroluminescent device with advantages such as simple fabrication process, low costs, easy formation of a flexible structure and a wide viewing angle. Therefore, the display technology utilizing organic light emitting diodes has become an important display technology.

[0003] At present, the light extraction efficiency of OLED displays is very low. The key reason is that the organic substance has a reflectivity higher than that of glass and air, while glass has a reflectivity higher than that of air, and therefore light emitted by the luminescent layer suffers from total reflection when traveling to the glass and air, resulting in absorption of partial light by the metal electrode. In order to solve this problem, micro-cavity top-emitting OLED displays have been developed, this structure changes light distribution by virtue of the multi-light interference phenomenon inside the organic layer to increase the light extraction efficiency.

SUMMARY

[0004] At least one embodiment of the present invention provides an OLED display and a manufacturing method thereof that allow the display to have optimal light extraction efficiency and viewing angle characteristics.

[0005] At least one embodiment of the present invention provides an OLED display including a plurality of sub-pixel units each including a first region and a second region. The first region includes a first electrode, a first organic material functional layer and a second electrode disposed in order on a base substrate. the second region includes a third electrode, a second organic material functional layer and a fourth electrode disposed in order on the base substrate. Both the first electrode and the third electrode comprise opaque a metal layer, and both the second electrode and the fourth electrode are translucent metal electrodes. The first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.

[0006] At least one embodiment of the present invention provides a manufacturing method of an OLED display including a plurality of sub-pixel units; the method including: forming a first electrode and a third electrode on a base substrate in a first region and a second region of each of the sub-pixel units respectively; the first electrode and the third electrode both comprising an opaque metal layer; Forming a first organic material functional layer and a second organic material functional layer in the first region and the second region respectively on the substrate formed with the first electrode and the third electrode, and Forming a second electrode and a fourth electrode in the first region and the second region respectively on the substrate formed with the first organic material functional layer and the second organic

material functional layer, the second electrode and the fourth electrode both being translucent metal electrodes. The first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.

BRIEF DESCRIPTION OF DRAWINGS

[0007] In order to explain the technical solution of embodiments of the present invention more clearly, accompanying drawings of the embodiments will be introduced briefly below. Obviously, the accompanying drawings in the following description only relate to some embodiments of the present invention rather than limiting the present invention.

[0008] FIG. 1 is a schematic top view of a sub-pixel unit of an OLED display provided in an embodiment of the present invention;

[0009] FIG. 2 is a schematic cross section view I in AA direction of a sub-pixel unit of an OLED display provided in an embodiment of the present invention;

[0010] FIG. 3 is a schematic cross section view II in AA direction of a sub-pixel unit of an OLED display provided in an embodiment of the present invention;

[0011] FIG. 4 is a schematic cross section view III in AA direction of a sub-pixel unit of an OLED display provided in an embodiment of the present invention;

[0012] FIG. 5 is a schematic cross section view IV in AA direction of a sub-pixel unit of an OLED display provided in an embodiment of the present invention;

[0013] FIG. 6 is a schematic cross section view I in AA direction of a sub-pixel unit of an OLED display including a planarization layer provided in an embodiment of the present invention;

[0014] FIG. 7 is a schematic cross section view II in AA direction of a sub-pixel unit of an OLED display including a planarization layer provided in an embodiment of the present invention;

[0015] FIG. 8 is a schematic cross section view I in AA direction of a sub-pixel unit of an OLED display including thin film transistors provided in an embodiment of the present invention;

[0016] FIG. 9 is a schematic cross section view II in AA direction of a sub-pixel unit of an OLED display including thin film transistors provided in an embodiment of the present invention; and

[0017] FIG. 10 is a schematic cross section view in AA direction of a sub-pixel unit of an OLED display including a buffer layer provided in an embodiment of the present invention.

REFERENCE NUMERALS

[0018] 01—Sub-pixel unit; 10—First region; 20—Second region; 100—Base substrate; 101—First electrode; 102—First organic material functional layer; 103—Second electrode; 201—Third electrode; 202—Second organic material functional layer; 203—Fourth electrode; 300—Planarization layer; 400—Thin film transistor; 500—Buffer layer; 600—Encapsulation layer.

DETAIL DESCRIPTION

[0019] In order to make objects, technical details and advantages of the embodiments of the invention apparent, the technical solutions of the embodiments will be described in a clearly and fully understandable way in connection with the drawings related to the embodiments of the invention. Apparently, the described embodiments are just a part but not all of the embodiments of the invention. Based on the described embodiments herein, those skilled in the art can obtain other embodiment(s), without any inventive work, which should be within the scope of the invention.

[0020] The inventors of the present application have noted that an OLED display typically implements regulation of strength of micro-cavity effect by adjusting the thickness from cathode to anode. However, if the micro-cavity effect is weak, the regulation of light extraction efficiency is not obvious, or even the light extraction efficiency becomes worse. If the micro-cavity effect is too strong, despite of the obvious regulation of light extraction efficiency, the viewing angle characteristics of the display become worse, and the intensity and color of light would be different at different viewing angles.

[0021] At least one embodiment of the present invention provides an OLED display as shown in FIGS. 1 to 10, including a plurality of sub-pixel units **01** each including a first region **10** and a second region **20**. The first region **10** includes a first electrode **101**, a first organic material functional layer **102** and a second electrode **103** disposed in order on a base substrate **100**. The second region **20** includes a third electrode **201**, a second organic material functional layer **202** and a fourth electrode **203** disposed in order on the base substrate **100**.

[0022] Both the first electrode **101** and the third electrode **201** include an opaque a metal layer, and both the second electrode **103** and the fourth electrode **203** are translucent metal electrodes. The first electrode **101**, the first organic material functional layer **102** and the second electrode **103** constitute a first micro-cavity, the third electrode **201**, the second organic material functional layer **202** and the fourth electrode **203** constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.

[0023] The first electrode **101** and the third electrode **201** may include an opaque metal layer and indium tin oxide (ITO) layers disposed on both sides of the opaque metal layer. This structure enables the first electrode **101** and the third electrode **201** to match the organic material functional layer over it in terms of energy level and helps to inject carriers in the first electrode **101** and the third electrode **201** into the luminescent layer of the organic material functional layer.

[0024] The second electrode **103** and the fourth electrode **203** may be a silver conducting layer with a relatively small thickness.

[0025] It is to be noted that, first of all, the first electrode **101** in the first region **10** and the third electrode **201** in the second region **20** may be anodes, and the second electrode **103** in the first region **10** and the fourth electrode **203** in the second region **20** may be cathodes. Alternatively, the first electrode **101** and the third electrode **201** may be cathodes, and the second electrode **103** and the fourth electrode **203** may be anodes.

[0026] As for the first organic material functional layer **102** in the first region **10** and the second organic material functional layer **202** in the second region **20**, they can include at

least an electron transport layer, a luminescent layer and a hole transport layer. Based on this configuration, in order to enhance the efficiency of injecting electrons and holes into the luminescent layer, the above-mentioned organic material functional layer may further include an electron injection layer, disposed between the cathode and the electron transport layer, and a hole injection layer, disposed between the hole transport layer and the anode.

[0027] Based on this, while applying an operation voltage across the anode and the cathode, holes in the anode and electrons in the cathode are both injected into the luminescent layer. Holes and electrons meet in the luminescent layer to recombine to form electron-hole pairs, and are excited then to release energy. The energy is given off in form of light, appears as light in different colors emitted by different luminescent molecules in the luminescent layer and exits homogeneously from both sides of the organic material functional layer.

[0028] For example, the luminescent layers of three sub-pixel units **01** in one pixel unit may include red, green and blue luminescent molecules respectively. Of course, the above-mentioned luminescent layer may also include only white luminescent molecules, which is not limited herein. These organic luminescent materials may be a fluorescent luminescent material, a phosphorescent luminescent material, or a mixture of both.

[0029] Secondly, considering that for the first region **10** or the second region **20**, the luminescent layers in the first organic material functional layer **102** and the second organic material functional layer **202** can emit light only when the first electrode **101** and the second electrode **103**, the third electrode **201** and the fourth electrode **203** are in operation, and the first region **10** and the second region **20** belong to the same sub-pixel unit **01**, in at least one embodiment of the present invention, it is possible to electrically connect the first electrode **101** and the third electrode **103**, and electrically connect the second electrode **201** and the fourth electrode **203**. For convenient fabrication, the layers in the first organic material functional layer **102** and the layers in the second organic material functional layer **202** may be formed at the same time.

[0030] Thirdly, the micro-cavity effect mainly means that the density redistribution of photons with different energy states such that only light of a specific wavelength conforming to a cavity mode can exit at a certain angle.

[0031] Thus the first region **10** and the second region **20** are endowed with different light extraction efficiencies and viewing angle characteristics by regulating parameters in the first micro-cavity and the second micro-cavity that influence the micro-cavity effect, for example, reasonably setting the thicknesses of the first micro-cavity and the second micro-cavity, and reflectivity of the first electrode **101** in the first micro-cavity and the third electrode **201** in the second micro-cavity. Based on this, it is possible to implement regulation of the light extraction efficiency and viewing angle characteristic of the sub-pixel unit **01** by adjusting the ratio between and the positions of the first region **10** and the second region **20**, thereby endowing the OLED display with the optimal light extraction efficiency and viewing angle characteristics.

[0032] Fourthly, the OLED display may be a passive matrix display or an active matrix display, which is not limited herein.

[0033] Fifthly, the accompanying drawings for all embodiments of the present invention schematically depict patterned

layers related to the spirit of the invention, and do not depict or only depict partial patterned layers irrelevant to the spirit.

[0034] At least one embodiment of the present invention provides an OLED display including a plurality of sub-pixel units **01** each including a first region **10** and a second region **20**. The first region **10** includes a first electrode **101**, a first organic material functional layer **102** and a second electrode **103** disposed in order on a base substrate **100**. The second region **20** includes a third electrode **201**, a second organic material functional layer **202** and a fourth electrode **203** disposed in order on the base substrate **100**. Both the first electrode **101** and the third electrode **201** include an opaque a metal layer, and both the second electrode **103** and the fourth electrode **203** are translucent metal electrodes. The first electrode **101**, the first organic material functional layer **102** and the second electrode **103** constitute a first micro-cavity; the third electrode **201**, the second organic material functional layer **202** and the fourth electrode **203** constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.

[0035] The first region **10** and the second region **20** are endowed with different light extraction efficiency and viewing angle characteristics by adjusting parameters in the first micro-cavity and the second micro-cavity that influence the micro-cavity effect. Based on this, it is possible to implement regulation of the light extraction efficiency and viewing angle characteristics of the sub-pixel unit **01** by reasonably setting the ratio between the first region **10** and the second region **20** and the positions of them, thereby endowing the OLED display with the optimal light extraction efficiency and viewing angle characteristics.

[0036] In at least one embodiment of the present invention, as shown in FIG. 2, the first micro-cavity has a thickness different from that of the second micro-cavity.

[0037] The thickness of the micro-cavity and the peak wavelength of the luminescent spectrum of the micro-cavity may satisfy the following relationship:

$$L = m \frac{\lambda_m}{2};$$

[0038] where m is the order of the emitting film; λ_m is the wavelength of the film of order m .

[0039] As can be known from the above description, it is possible to change the position of emission mode order “ m ” and the emission wavelength of the micro-cavity by adjusting the thickness of the micro-cavity, thereby shifting the central wavelength of the electroluminescence spectrum, hence changing the light extraction efficiency. Based on this, the light extraction efficiency and the viewing angle characteristics of the sub-pixel unit **01** can be balanced by adjusting the thicknesses of the first micro-cavity and the second micro-cavity.

[0040] Here, for example, the thickness of the first micro-cavity is regulated by adjusting the thickness of the first electrode **101**, and the thickness of the second micro-cavity is regulated by adjusting the thickness of the third electrode **201**.

[0041] In at least one embodiment of the present invention, the first electrode **101** and the third electrode **201** have different reflectivity.

[0042] Since the micro-cavity effect primarily relates to a multi-light interference phenomenon formed by multiple

reflections of light between two electrodes and enhancing light extraction efficiency by changing light distribution, it is possible to reasonably set the reflectivity of reflecting electrodes, namely reflectivity of the first electrode **101** and third electrode **201** to, for example, endow the first region **10** with a high light extraction efficiency and use the second region **20** guarantee the viewing angle characteristic, thereby achieving an optimal balanced state of light extraction efficiency and viewing angle characteristic of the sub-pixel unit **01**.

[0043] In at least one embodiment of the present invention, it is possible to make the first electrode **101** and the third electrode **201** have different reflectivity by changing shapes of the top surface of the first electrode **101** that contacts the first organic material functional layer **102** and the top surface of the third electrode **201** that contacts the second organic material functional layer **202**. That is, as shown in FIGS. 3 to 5, it is possible to set the top surface of the first electrode **101** that contacts the first organic material functional layer **102** as a plane, and set the top surface of the third electrode **201** that contacts the second organic material functional layer **202** as a non-planar surface.

[0044] In this way, by setting the top surface of the third electrode **201** that contacts the second organic material functional layer **202** to be a non-planar surface, it can cause the light emitted from the luminescent layer of the second organic material functional layer **202** to generate multiple-beam interference in directions between the third electrode **201** and fourth electrode **203**, and enable light of different angles to exit, thereby guaranteeing its viewing angle characteristics; while by setting the top surface of the first electrode **101** that contacts the first organic material functional layer **102** to be a plane, it can guarantee the intensity of its emergent light. Combining both of them, it is possible to achieve an optimal balanced state of light extraction efficiency and viewing angle characteristics of the sub-pixel unit **01**.

[0045] Based on this, the process of setting the top surface of the third electrode **201** that contacts the second organic material functional layer **202** to be a non-planar surface may be implemented in the following ways.

[0046] The first way. As shown in FIG. 3, the top surface of the third electrode **201** that contacts the second organic material functional layer **202** is formed with certain roughness. The value of roughness may be set according to practical situations.

[0047] The second way. As shown in FIGS. 4 and 5, the top surface of the third electrode **201** that contacts the second organic material functional layer **202** is formed into an uneven shape. Here, the uneven shape may be for example in arcs, waves and corrugated shape.

[0048] In at least one embodiment of the present invention, as shown in FIGS. 6 and 7, in the above-mentioned ways, it is possible to form the top surface of the third electrode **201** into a non-planar shape by providing a planarization layer **300** between the base substrate **100** and the first electrodes **101** as well as the third electrode **201**. That is, it is possible to configure the top surface of the planarization layer **300** under the third electrode **201** with a roughness of predetermined amount or an uneven shape.

[0049] This is because the planarization layer **300** is located under the first electrode **101** and third electrode **201**, that is, the underlying planarization layer **300** needs to be formed firstly, and then the upper first electrode **101** and third electrode **201** are formed. Therefore, if the top surface of the planarization layer **300** under the third electrode **201** has

certain roughness or a particular shape, the third electrode **201** formed thereon also have certain roughness or a particular shape, and in like manner, the second organic material functional layer **202** and the fourth electrode **203** over the third electrode **201** also have certain roughness or a particular shape.

[0050] Further, considering that passive matrix driving has deficient aspects when it is applied to large-sized displays, in at least one embodiment of the present invention, the OLED display provided in an embodiment of the present invention is an active matrix type OLED display. That is, as shown in FIGS. **8** and **9**, each sub-pixel unit **01** of the OLED display may further include a thin film transistor **400** disposed between the base substrate **100** and the first electrode **101** or the third electrode **201**. The thin film transistor **400** includes a gate electrode, a gate insulating layer, a semiconductor active layer, a source electrode and a drain electrode. Based on this, the OLED display further includes gate lines, gate line leads (not shown in drawings) electrically connected with the gate electrodes, and data lines, data line leads (not shown in figures) electrically connected with the source electrodes.

[0051] It is to be noted that the thin film transistor **400** may be of a top gate type or a bottom gate type, and the present invention is not limited thereto.

[0052] In addition to the structures as shown in FIGS. **8** and **9**, the thin film transistor **400** may also be disposed on the encapsulation layer and the drain electrode of the thin film transistor **400** is electrically connected with the anode or cathode of the luminescent unit on the base substrate.

[0053] Furthermore, in the case that the first electrode **101** and the third electrode **201** are electrically connected, and the second electrode **103** and the fourth electrode **203** are electrically connected, in order to electrically connect the drain electrode with the second electrode **103**, it is necessarily required to electrically connect the second electrode **103** with the drain electrode through both the first organic material functional layer **102** and the first electrode **101**. This could result in short circuit between the second electrode **103** and the first electrode **101** on one hand, and on the other hand, the manufacturing process is relatively complex due to the material property of the organic material functional layer. In view of this, in at least one embodiment of the present invention, the drain electrode directly contacts the first electrode **101** or the third electrode **201**. As shown in FIG. **9**, in the case that the OLED display includes a planarization layer **300** under the first electrode **101** and the third electrode **201**, it is required to electrically connect the first electrode **101** or the third electrode **201** with the drain electrode of the thin film transistor **400** through via holes formed in the planarization layer **300**.

[0054] In at least one embodiment of the present invention, as shown in FIG. **10**, the OLED display further includes a buffer layer **500** disposed between the base substrate **100** and the thin film transistor **400**, and the buffer layer **500** contacts the base substrate **100**.

[0055] The buffer layer **500** may be of a single-layer or multi-layer structure and may be formed of a material, for example, SiN (silicon nitride) or SiO_x (silicon oxide).

[0056] The buffer layer **500** helps to improve the smoothness and adhesion of the surface of the base substrate **10**, and improve the anti-permeability against water and oxygen.

[0057] It is to be noted that due to the material property of the organic material functional layer, in at least one embodiment of the present invention, the OLED display should further include an encapsulation layer **600** for encapsulating

organic material; the encapsulation layer **600** may be of a film encapsulation type or a substrate encapsulation type, which is not limited herein.

[0058] At least one embodiment of the present invention further provides a manufacturing method of an OLED display including a plurality of sub-pixel units. Referring to FIG. **2**, the method includes the following steps:

[0059] S101, forming a first electrode **101** and a third electrode **201** on a base substrate **100** in a first region **10** and a second region **20** of each of the sub-pixel units **01** respectively; the first electrode **101** and the third electrode **201** both including an opaque metal layer;

[0060] S102, forming a first organic material functional layer **102** and a second organic material functional layer **202** in the first region **10** and the second region **20** respectively on the substrate formed with the first electrode **101** and the third electrode **201**, and

[0061] S103, forming a second electrode **103** and a fourth electrode **203** in the first region **10** and the second region **20** respectively on the substrate formed with the first organic material functional layer **102** and the second organic material functional layer **202**, the second electrode **103** and the fourth electrode **203** both being translucent metal electrodes.

[0062] The first electrode **101**, the first organic material functional layer **102** and the second electrode **103** constitute a first micro-cavity, the third electrode **201**, the second organic material functional layer **202** and the fourth electrode **203** constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different thicknesses.

[0063] Here, for example, the thickness of the first micro-cavity may be regulated by adjusting the thickness of the first electrode **101**, and the thickness of the second micro-cavity may be regulated by adjusting the thickness of the third electrode **201**.

[0064] As can be known from the above-mentioned relationship between the micro-cavity thickness and the wavelength of luminescent spectrum of micro-cavity, it is possible to change the position of emission mode order "m" and the emission wavelength of the micro-cavity by adjusting the thickness of the micro-cavity, thereby shifting the central wavelength of the electroluminescence spectrum, hence changing the light extraction efficiency. Therefore, in at least one embodiment of the present invention, the first region **10** and the second region **20** may have different light extraction efficiencies and viewing angle characteristics by adjusting the thicknesses of the first micro-cavity and the second micro-cavity. Thus, it is possible to implement regulation of the light extraction efficiency and viewing angle characteristics of the sub-pixel unit **01** by adjusting the ratio between the first region **10** and the second region **20** and the positions of them, thereby endowing the OLED display with the optimal light extraction efficiency and viewing angle characteristics.

[0065] Referring to FIG. **8**, in each of the sub-pixel units **01**, a thin film transistor **400** is further formed between the base substrate **100** and the first electrode **101** or the third electrode **201**.

[0066] The thin film transistor **400** includes a gate electrode, a gate insulating layer, a semiconductor active layer, a source electrode and a drain electrode; and the drain electrode directly contacts the first electrode **101** or the third electrode **201**.

[0067] At least one embodiment of the present invention further provides a manufacturing method of an OLED display

including a plurality of sub-pixel units. Referring to FIGS. 3 to 5, the method includes the following steps:

[0068] S201, forming a first electrode 101 and a third electrode 201 on a base substrate 100 in a first region 10 and a second region 20 of each of the sub-pixel units 01 respectively; the first electrode 101 and the third electrode 201 both including an opaque metal layer, and the first electrode 101 having a planar top surface while the third electrode 201 having a non-planar top surface;

[0069] S202, forming a first organic material functional layer 102 and a second organic material functional layer 202 in the first region 10 and the second region 20 respectively on the substrate formed with the first electrode 101 and the third electrode 201;

[0070] S203, forming a second electrode 103 and a fourth electrode 203 in the first region 10 and the second region 20 respectively on the substrate formed with the first organic material functional layer 102 and the second organic material functional layer 202, the second electrode 103 and the fourth electrode 203 both being translucent metal electrodes.

[0071] The first electrode 101, the first organic material functional layer 102 and the second electrode 103 constitute a first micro-cavity, and the third electrode 201, the second organic material functional layer 202 and the fourth electrode 203 constitute a second micro-cavity.

[0072] In the embodiment of the present invention, by setting the top surface of the third electrode 201 to be non-planar, it is possible to enable the light emitted from the luminescent layer of the second organic material functional layer 202 to form multiple-beam interference in directions between the third electrode 201 and the fourth electrode 203, allowing light in different angles to exit and hence guaranteeing its viewing angle characteristics. While by setting the top surface of the first electrode 101 to be a plane, it can guarantee the intensity of the emitted light. By combining both of them, it is possible to achieve an optimal balanced state of the light extraction efficiency and the viewing angle characteristics of the sub-pixel unit 01, thereby endowing the OLED display with optimal light extraction efficiency and viewing angle characteristics.

[0073] Based on this, the process of setting the top surface of the third electrode 201 to be non-planar may be implemented in the following two ways.

[0074] The first way. As shown in FIG. 3, the top surface of the third electrode 201 that contacts the second organic material functional layer 202 is formed with certain roughness. The value of roughness may be set according to practical situations.

[0075] The second way. As shown in FIGS. 4 and 5, the top surface of the third electrode 201 that contacts the second organic material functional layer 202 is formed into an uneven shape. Here, the uneven shape may be for example of arcs, waves and corrugated shape.

[0076] Referring to FIGS. 6 and 7, the above-mentioned two cases may be implemented by forming a planarization layer 300 between the base substrate 100 and the first electrode 101 as well as the third electrode 201. That is, forming the planarization layer 300 specifically includes: forming a planarization layer film on the base substrate 100; and dry etching the planarization layer film such that the surface of the planarization layer film have roughness of a predetermined value or an uneven shape to form the planarization layer 300.

[0077] The material for the planarization layer film may be resin, and a corresponding dry etching gas may be selected to

form a plasma atmosphere for etching the planarization layer film, thereby increasing its roughness or forming a particular shape in the second region 20.

[0078] Of course, it is also possible to control the shape of the planarization layer 300 in the second region 20 by the selection of heat treatment or drying process on the material itself.

[0079] In this process, it is required to guarantee the top surface of the planarization layer 300 in the first region 10 is a plane.

[0080] Referring to FIG. 9, in each of the sub-pixel units 01, a thin film transistor 400 is further formed between the base substrate 100 and the first electrode 101 or the third electrode 201.

[0081] The drain electrode of the thin film transistor 400 directly contacts the first electrode 101 or the third electrode 201.

[0082] The method of the above-mentioned embodiment allows the first micro-cavity and the second micro-cavity in one sub-pixel to have different micro-cavity effects.

[0083] What are described above is related to the illustrative embodiments of the disclosure only and not limitative to the scope of the disclosure; the scopes of the disclosure are defined by the accompanying claims.

[0084] The present application claims priority of a China patent application No. 201410171612.7 filed on Apr. 25, 2014, which is incorporated in its entirety herein by reference as part of the present application.

1. An organic light-emitting diode (OLED) display comprising a plurality of sub-pixel units,

wherein each of the sub-pixel units comprises a first region and a second region; the first region comprises a first electrode, a first organic material functional layer and a second electrode disposed in order on the base substrate; and the second region comprises a third electrode, a second organic material functional layer and a fourth electrode disposed in order on the base substrate;

wherein both the first electrode and the third electrode comprise opaque a metal layer, and both the second electrode and the fourth electrode are translucent metal electrodes;

the first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different micro-cavity effects.

2. The OLED display of claim 1, wherein the first micro-cavity has a thickness different from that of the second micro-cavity.

3. The OLED display of claim 1, wherein the first electrode and the third electrode have different reflectivity.

4. The OLED display of claim 3, wherein for the first micro-cavity, a top surface of the first electrode that contacts the first organic material functional layer is a plane; and for the second micro-cavity, a top surface of the third electrode that contacts the second organic material functional layer is a non-planar surface.

5. The OLED display of claim 4, wherein a top surface of the third electrode that contacts the second organic material functional layer has roughness of a predetermined value.

6. The OLED display of claim 4, wherein a top surface of the third electrode that contacts the second organic material functional layer has an uneven shape.

7. The OLED display of claim 5, further comprising:
a planarization layer disposed between the base substrate and the first electrode as well as the third electrode;
wherein a top surface of the planarization layer under the third electrode has roughness of a predetermined value or an uneven shape.

8. The OLED display of claim 1, wherein each of the sub-pixel units further comprises a thin film transistor disposed between the base substrate and the first electrode or the third electrode.

9. The OLED display of claim 8, wherein the first electrode and the third electrode are electrically connected, the second electrode and the fourth electrode are electrically connected; and

a drain electrode of the thin film transistor is electrically connected with the first electrode and the third electrode.

10. A manufacturing method of an organic light-emitting diode (OLED) display comprising a plurality of sub-pixel units, the method comprising:

forming a first electrode and a third electrode on a base substrate in a first region and a second region of each of the sub-pixel units respectively; the first electrode and the third electrode both comprising an opaque metal layer;

forming a first organic material functional layer and a second organic material functional layer in the first region and the second region respectively on the substrate formed with the first electrode and the third electrode, and

forming a second electrode and a fourth electrode in the first region and the second region respectively on the substrate formed with the first organic material functional layer and the second organic material functional layer, the second electrode and the fourth electrode both being translucent metal electrodes,

wherein the first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity, and the first micro-cavity and the second micro-cavity have different thicknesses.

11-16. (canceled)

17. The OLED display of claim 6, further comprising:
a planarization layer disposed between the base substrate and the first electrode as well as the third electrode;
wherein a top surface of the planarization layer under the third electrode has roughness of a predetermined value or an uneven shape.

18. The OLED display of claim 2, wherein each of the sub-pixel units further comprises a thin film transistor disposed between the base substrate and the first electrode or the third electrode.

19. The OLED display of claim 3, wherein each of the sub-pixel units further comprises a thin film transistor disposed between the base substrate and the first electrode or the third electrode.

20. The OLED display of claim 4, wherein each of the sub-pixel units further comprises a thin film transistor disposed between the base substrate and the first electrode or the third electrode.

21. The method of claim 10, further comprising:

forming a thin film transistor between the base substrate and the first electrode or the third electrode in each of the sub-pixel units.

22. A manufacturing method of an organic light-emitting diode (OLED) display comprising a plurality of sub-pixel units, the method comprising:

forming a first electrode and a third electrode on a base substrate in a first region and a second region of each of the sub-pixel units respectively; the first electrode and the third electrode both comprising an opaque metal layer, and a top surface of the first electrode is a plane, a top surface of the third electrode is a non-planar surface;
forming a first organic material functional layer and a second organic material functional layer in the first region and the second region respectively on the substrate formed with the first electrode and the third electrode, and

forming a second electrode and a fourth electrode in the first region and the second region respectively on the substrate formed with the first organic material functional layer and the second organic material functional layer, the second electrode and the fourth electrode both being translucent metal electrodes,

wherein the first electrode, the first organic material functional layer and the second electrode constitute a first micro-cavity, the third electrode, the second organic material functional layer and the fourth electrode constitute a second micro-cavity.

23. The method of claim 22, wherein a top surface of the third electrode has roughness of a predetermined value or an uneven shape;

the method further comprising: forming a planarization layer between the base substrate and the first electrode as well as the third electrode;

wherein forming of the planarization layer comprises:

forming a planarization layer film on the base substrate;
dry etching the planarization layer film in the second region to allow a surface of the planarization layer film to have roughness of a predetermined value or an uneven shape, thereby forming the planarization layer.

24. The method of claim 22, further comprising:

forming a thin film transistor between the base substrate and the first electrode or the third electrode in each of the sub-pixel units.

25. The method of claim 23, further comprising:

forming a thin film transistor between the base substrate and the first electrode or the third electrode in each of the sub-pixel units.

* * * * *

专利名称(译)	OLED显示器及其制造方法		
公开(公告)号	US20160254493A1	公开(公告)日	2016-09-01
申请号	US14/436014	申请日	2014-08-07
[标]申请(专利权)人(译)	京东方科技集团股份有限公司		
申请(专利权)人(译)	京东方张婷婷GROUP CO. , LTD.		
当前申请(专利权)人(译)	京东方科技集团股份有限公司.		
[标]发明人	SUN LIANG		
发明人	SUN, LIANG		
IPC分类号	H01L51/52 H01L51/56 H01L27/32		
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优先权	201410171612.7 2014-04-25 CN		
其他公开文献	US9673421		
外部链接	Espacenet USPTO		

摘要(译)

提供一种有机发光二极管 (OLED) 显示器及其制造方法。OLED显示器包括多个子像素单元，每个子像素单元包括第一区域和第二区域。第一区域包括在基底上依次设置的第一电极，第一有机材料功能层和第二电极。第二区域包括依次设置在基底上的第三电极，第二有机材料功能层和第四电极。第一电极和第三电极均包括不透明金属层，第二电极和第四电极是半透明金属电极。第一电极，第一有机材料功能层和第二电极构成第一微腔，第三电极，第二有机材料功能层和第四电极构成第二微腔，第一微腔和第一微腔第二微腔具有不同的微腔效应。

